

Improved Quad CMOS Analog Switches

Features

- $\pm 22\text{-V}$ Supply Voltage Rating
- CMOS Compatible Logic
- Low On-Resistance— $r_{DS(on)}$: $45\ \Omega$
- Low Leakage— $I_{D(on)}$: $20\ \text{pA}$
- Single Supply Operation Possible
- Extended Temperature Range
- Fast Switching— t_{ON} : $< 200\ \text{ns}$
- Low Glitching— Q : $1\ \text{pC}$

Benefits

- Wide Analog Signal Range
- Simple Logic Interface
- Higher Accuracy
- Minimum Transients
- Reduced Power Consumption
- Superior to DG308A/309

Applications

- Industrial Instrumentation
- Test Equipment
- Communications Systems
- Disk Drives
- Computer Peripherals
- Portable Instruments
- Sample-and-Hold Circuits

Description

The DG308B/309B analog switches are highly improved versions of the industry-standard DG308A/309. These devices are fabricated in Siliconix' proprietary silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

These quad single-pole single-throw switches are designed for a wide variety of applications in telecommunications, instrumentation, process control, computer peripherals, etc. An improved charge injection compensation design

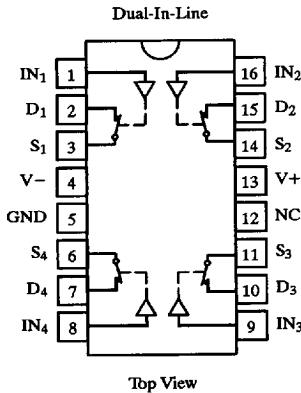
minimizes switching transients. The DG308B and DG309B can handle up to $\pm 22\text{-V}$ input signals. An epitaxial layer prevents latchup.

All devices feature true bi-directional performance in the on condition, and will block signals to the supply levels in the off condition.

The DG308B is a normally open switch and the DG309B is a normally closed switch. (See Truth Table.)

Functional Block Diagram and Pin Configuration

DG308B



Truth Table

Logic	DG308B	DG309B
0	OFF	ON
1	ON	OFF

Logic "0" $\leq 3.5\text{V}$

Logic "1" $\geq 11\text{V}$

Switches Shown for DG308B Logic "1" Input

Ordering Information

Temp Range	Package	Part Number
$-40\text{ to }85^\circ\text{C}$	16-Pin Plastic DIP	DG308BDJ
		DG309BDJ
	16-Pin Narrow SOIC	DG308BDY
		DG309BDY
$-55\text{ to }125^\circ\text{C}$	16-Pin CerDIP	DG308BAK
		DG308BAK/883
		DG309BAK
		DG309BAK/883

Absolute Maximum Ratings

Voltages Referenced to V-

V+ 44 V

GND 25 V

Digital Inputs^a V_S, V_D (V-) -2 V to (V+) +2 V
or 30 mA, whichever occurs first

Current, Any Terminal 30 mA

Peak Current, S or D

(Pulsed at 1 ms, 10% duty cycle max) 100 mA

Storage Temperature (AK, Suffix) -65 to 150°C

(DJ, DY Suffix) -65 to 125°C

Power Dissipation (Package)^b

16-Pin Plastic DIP^c 470 mW

16-Pin Narrow SOIC^d 640 mW

16-Pin CerDIP^e 900 mW

Notes:

a. Signals on S_X, D_X, or I_{NX} exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC Board.

c. Derate 6.5 mW/°C above 75°C

d. Derate 7.6 mW/°C above 75°C

e. Derate 12 mW/°C above 75°C

Specifications^a

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V- = -15 V VIN = 11 V, 3.5 V ^f	Temp ^b	Typ ^c	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min ^d	Max ^d	Min ^d	Max ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}	V _D = ± 10 V, I _S = 1 mA	Full		-15	15	-15	15	V
Drain-Source On-Resistance	r _{DS(on)}		Room Full	45		85 100		85 100	Ω
r _{DS(on)} Match	Δr _{DS(on)}		Room	2					%
Source Off Leakage Current	I _{S(off)}	V _S = ± 14 V, V _D = ∓ 14 V	Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	nA
Drain Off Leakage Current	I _{D(off)}	V _D = ± 14 V, V _S = ∓ 14 V	Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	
Drain On Leakage Current	I _{D(on)}	V _S = V _D = 14 V	Room Full	± 0.02	-0.5 -40	0.5 40	-0.5 -10	0.5 10	
Digital Control									
Input Voltage High	V _{INH}	VINH or VINL	Full		11		11		V
Input Voltage Low	V _{INL}		Full			3.5		3.5	
Input Current	I _{INH} or I _{INL}		Full		-1	1	-1	1	μA
Input Capacitance	C _{IN}		Room	5					pF
Dynamic Characteristics									
Turn-On Time	t _{ON}	V _S = 3 V, See Figure 2	Room			200		200	ns
Turn-Off Time	t _{OFF}		Room			150		150	
Charge Injection	Q	C _L = 1000 pF, V _g = 0 V, R _g = 0 Ω	Room	1					pC
Source-Off Capacitance	C _{S(off)}	V _S = 0 V, f = 1 MHz	Room	5					pF
Drain-Off Capacitance	C _{D(off)}		Room	5					
Channel On Capacitance	C _{D(on)}	V _D = V _S = 0 V, f = 1 MHz	Room	16					
Off Isolation	OIRR	C _L = 15 pF, R _L = 50 Ω	Room	90					dB
Channel-to-Channel Crosstalk	X _{TALK}	V _S = 1 V _{RMS} , f = 100 kHz	Room	95					

Specifications^a

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V- = -15 V VIN = 11 V, 3.5 V ^f	Temp ^b	Typ ^c	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min ^d	Max ^d	Min ^d	Max ^d	
Power Supply									
Positive Supply Current	I+	VIN = 0 or 15 V	Room Full			15		15	μA
Negative Supply Current	I-		Room Full		-1-5		-1-5		
Power Supply Range for Continuous Operation	VOP		Full		±4	±22	±4	±22	V

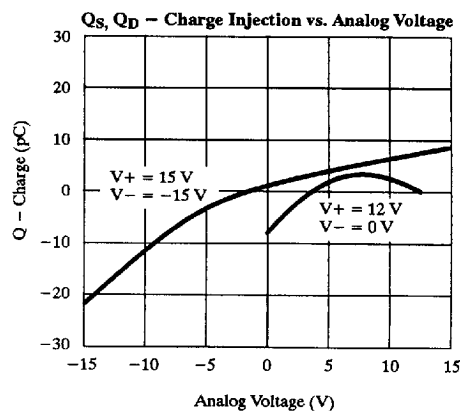
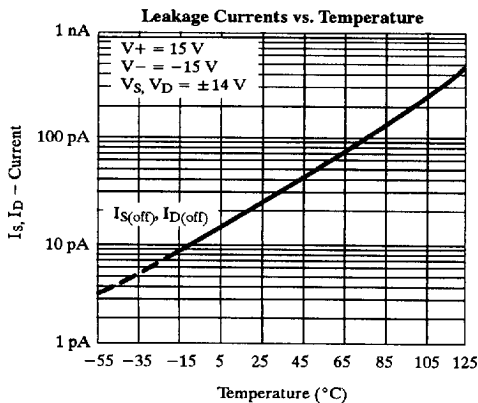
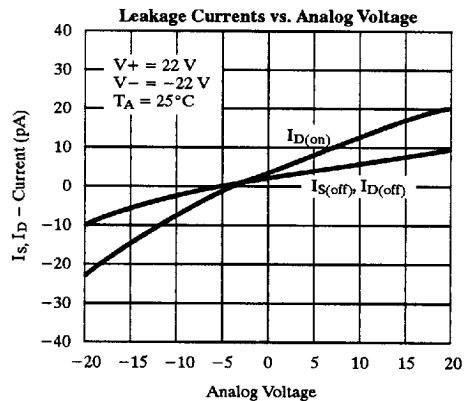
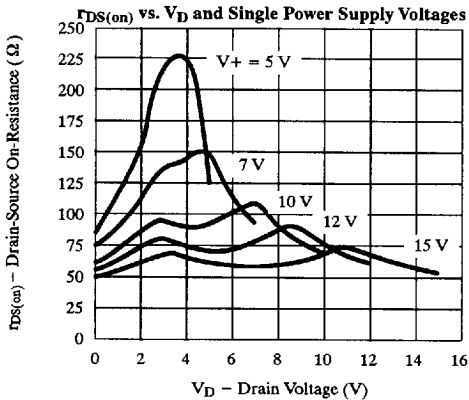
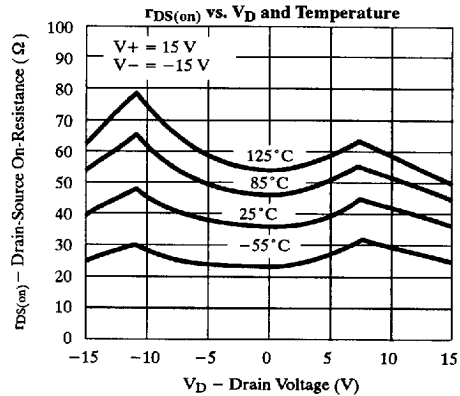
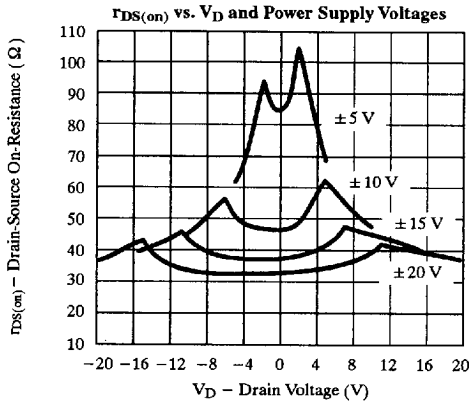
Specifications^a for Single Supply

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 12 V, V- = 0 V VIN = 11 V, 3.5 V ^f	Temp ^b	Typ ^c	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min ^d	Max ^d	Min ^d	Max ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	r _{DS(on)}	V _D = 3 V, 8 V, I _S = 1 mA	Room Full	90		160 200		160 200	Ω
Dynamic Characteristics									
Turn-On Time	t _{ON}	V _S = 8 V, See Figure 2	Room			300		300	ns
Turn-Off Time	t _{OFF}		Room			200		200	
Charge Injection	Q	C _L = 1 nF, V _{gen} = 6 V, R _{gen} = 0 Ω	Room	4					pC
Power Supply									
Positive Supply Current	I+	VIN = 0 or 12 V	Room Full			15		15	μA
Negative Supply Current	I-		Room Full		-1 -5		-1 -5		
Power Supply Range for Continuous Operation	V _{OP}		Full		4	44	4	44	V

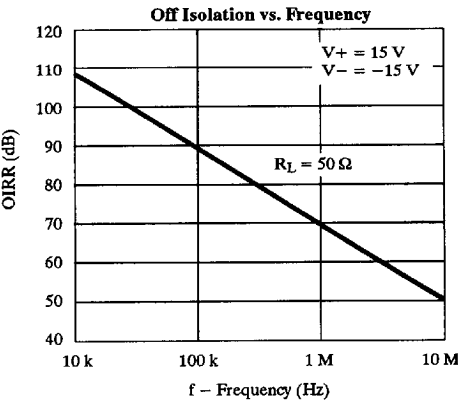
Notes:

- Refer to PROCESS OPTION FLOWCHART (Section 5 of the 1994 Data Book or FaxBack number 7103).
- Room = 25°C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.

Typical Characteristics



Typical Characteristics (Cont'd)



Schematic Diagram (Typical Channel)

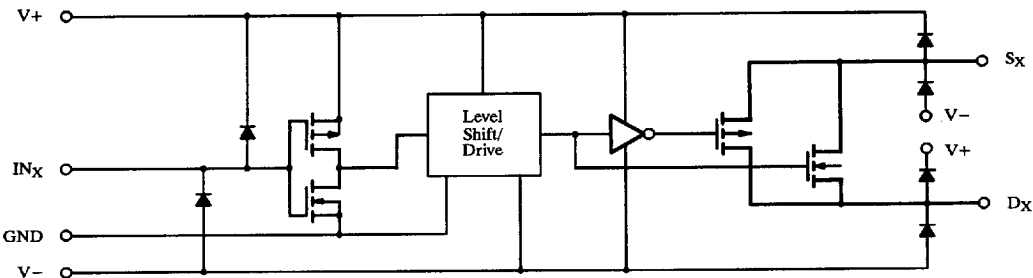


Figure 1.

Test Circuits

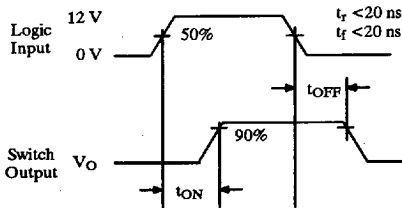
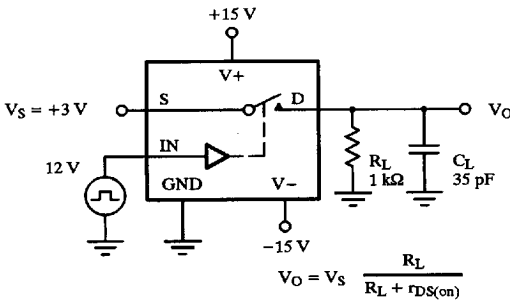


Figure 2. Switching Time

Test Circuits (Cont'd)

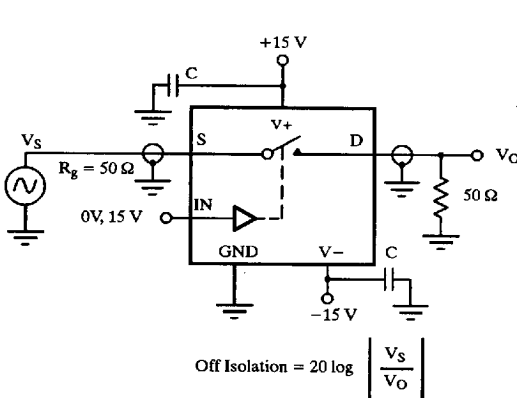


Figure 3. Off Isolation

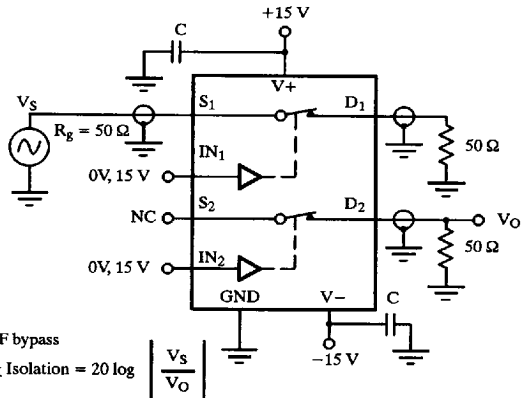


Figure 4. Channel-to-Channel Crosstalk

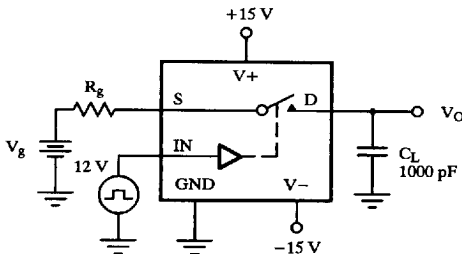


Figure 5. Charge Injection

Applications

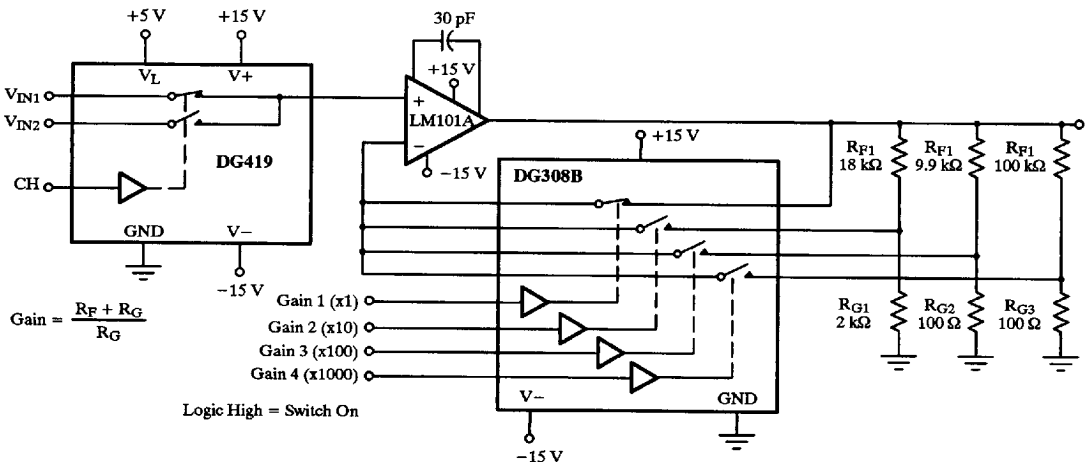


Figure 7. A Precision Amplifier with Digitally Programmable Inputs and Gains

Applications (Cont'd)

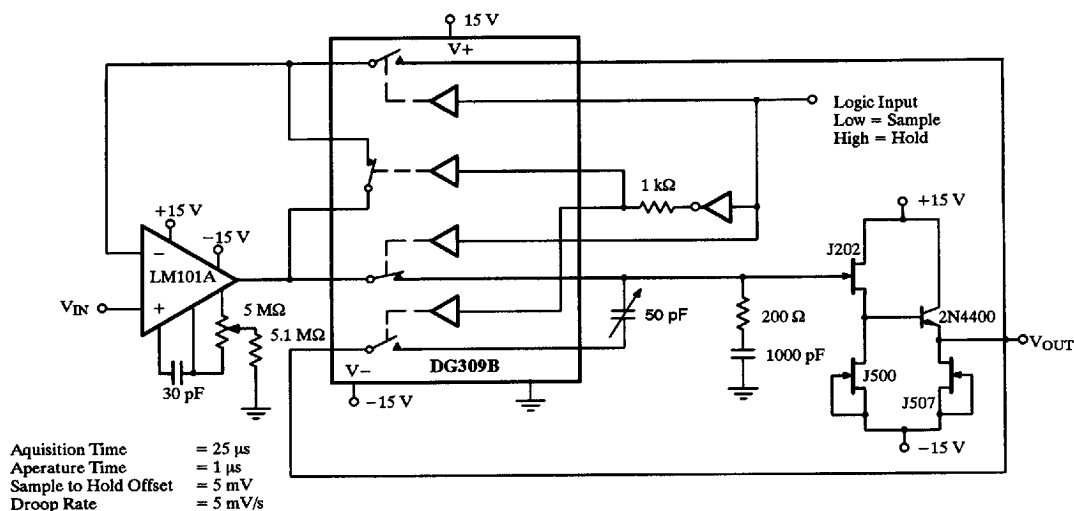


Figure 8. Sample-and-Hold

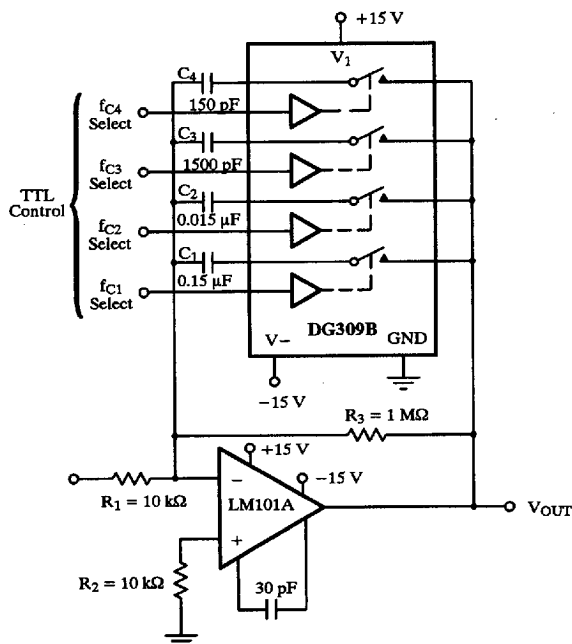
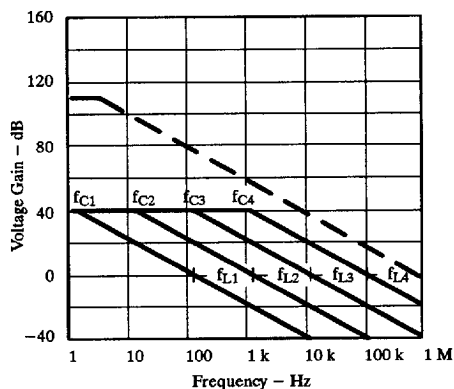


Figure 9. Active Low Pass Filter with Digitally Selected Break Frequency



$$A_L \text{ (Voltage Gain Below Break Frequency)} = \frac{R_3}{R_1} = 100 \text{ (40 dB)}$$

$$f_C \text{ (Break Frequency)} = \frac{1}{2\pi R_3 C_X}$$

$$f_L \text{ (Unity Gain Frequency)} = \frac{1}{2\pi R_1 C_X}$$

$$\text{Max Attenuation} = \frac{f_{DS(on)}}{10 \text{ kHz}} \approx -40 \text{ dB}$$